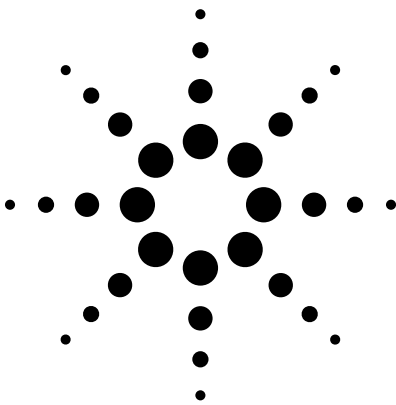


Agilent HCPL-181 Phototransistor Optocoupler SMD Mini-Flat Type Data Sheet



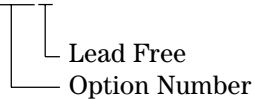
Description

The HCPL-181 contains a light emitting diode optically coupled to a phototransistor. It is packaged in a 4-pin mini-flat SMD package with a 2.0 mm profile. The small dimension of this product allows significant space saving. The package volume is 30% smaller than that of conventional DIP type. Input-output isolation voltage is 3750 Vrms. Response time, t_r , is typically 4 μ s and minimum CTR is 50% at input current of 5 mA.

Ordering Information

Specify part number followed by Option Number (if desired).

HCPL-181-XXXXE



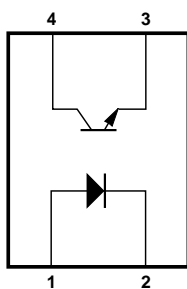
- 000 = No Options
- 060 = IEC/EN/DIN EN 60747-5-2 Option
- 00A = Rank Mark A
- 00B = Rank Mark B
- 00C = Rank Mark C
- 00D = Rank Mark D

Features

- **Current Transfer Ratio**
(CTR: min. 50% at $I_F = 5$ mA, $V_{CE} = 5$ V)
- **High input-output isolation voltage**
($V_{iso} = 3750$ Vrms)
- **High collector-emitter voltage** ($V_{CEO} = 80$ V)
- **Response time** (t_r : typ., 4 μ s at $V_{CE} = 2$ V, $I_C = 2$ mA, $R_L = 100 \Omega$)
- **Mini-flat package (2.0 mm profile) in tape and reel package**
- **UL approved**
- **CSA approved**
- **IEC/EN/DIN EN 60747-5-2 approved**
- **Options available:**
– IEC/EN/DIN EN 60747-5-2 approvals (060)

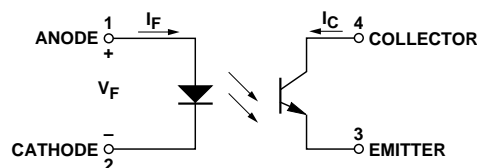
Functional Diagram

PIN NO. AND INTERNAL CONNECTION DIAGRAM



- 1. ANODE 3. EMITTER
- 2. CATHODE 4. COLLECTOR

Schematic



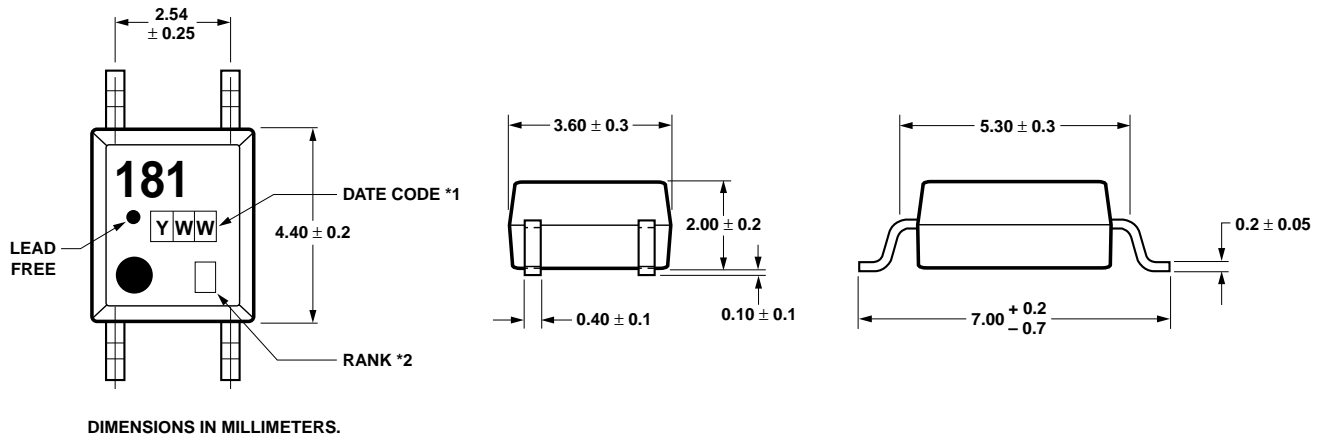
Applications

- I/O interfaces for computers
- System appliances, measuring instruments
- Signal transmission between circuits of different potentials and impedances
- Feedback circuit in power supply

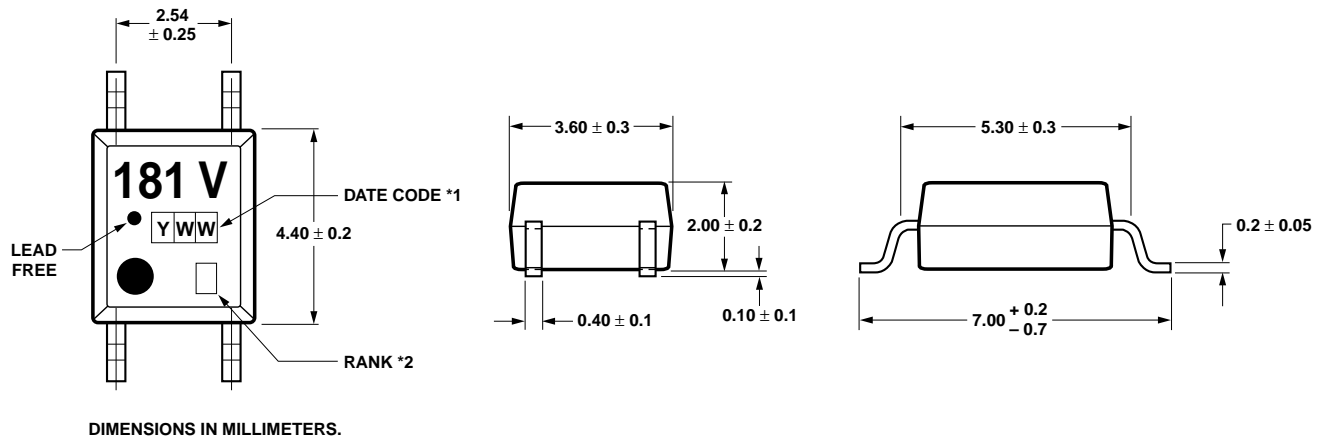
CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

Package Outline Drawings

HCPL-181-000E

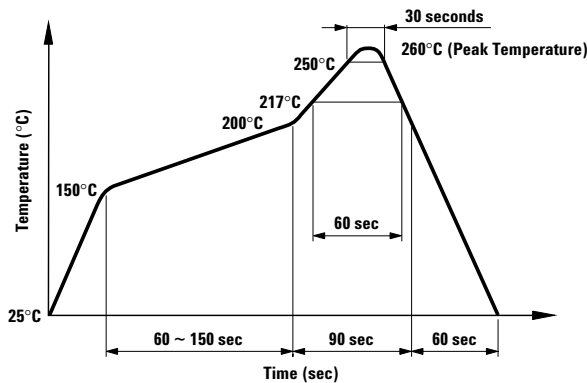


HCPL-181-060E



Solder Reflow Temperature Profile

- 1) One-time soldering reflow is recommended within the condition of temperature and time profile shown at right.
- 2) When using another soldering method such as infrared ray lamp, the temperature may rise partially in the mold of the device. Keep the temperature on the package of the device within the condition of (1) above.



Absolute Maximum Ratings (T_A = 25°C)

| | |
|---|-----------------|
| Storage Temperature, T _S | -55°C to +155°C |
| Operating Temperature, T _A | -55°C to +100°C |
| Lead Solder Temperature, max. (1.6 mm below seating plane) | 260°C for 10 s |
| Average Forward Current, I _F | 50 mA |
| Reverse Input Voltage, V _R | 6 V |
| Input Power Dissipation, P _I | 70 mW |
| Collector Current, I _C | 50 mA |
| Collector-Emitter Voltage, V _{CE0} | 80 V |
| Emitter-Collector Voltage, V _{ECO} | 6 V |
| Collector Power Dissipation | 150 mW |
| Total Power Dissipation | 170 mW |
| Isolation Voltage, V _{iso} (AC for 1 minute, R.H. = 40 ~ 60%) | 3750 Vrms |

| Rank Mark | CTR (%) | Conditions |
|-----------|-----------|--|
| A | 80 ~ 160 | I _F = 5 mA, V _{CE} = 5 V, T _A = 25°C |
| B | 130 ~ 260 | |
| C | 200 ~ 400 | |
| D | 300 ~ 600 | |

Electrical Specifications (T_A = 25°C)

| Parameter | Symbol | Min. | Typ. | Max. | Units | Test Conditions |
|--------------------------------------|----------------------|----------------------|----------------------|------|-------|---|
| Forward Voltage | V _F | - | 1.2 | 1.4 | V | I _F = 20 mA |
| Reverse Current | I _R | - | - | 10 | μA | V _R = 4 V |
| Terminal Capacitance | C _t | - | 30 | 250 | pF | V = 0, f = 1 KHz |
| Collector Dark Current | I _{CEO} | - | - | 100 | nA | V _{CE} = 20 V |
| Collector-Emitter Breakdown Voltage | BV _{CEO} | 80 | - | - | V | I _C = 0.1 mA, I _F = 0 |
| Emitter-Collector Breakdown Voltage | BV _{ECO} | 6 | - | - | V | I _E = 10 μA, I _F = 0 |
| Collector Current | I _C | 2.5 | - | 30 | mA | I _F = 5 mA, V _{CE} = 5 V |
| *Current Transfer Ratio | CTR | 50 | - | 600 | % | |
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | - | - | 0.2 | V | I _F = 20 mA, I _C = 1 mA |
| Response Time (Rise) | t _r | - | 4 | 18 | μs | V _{CC} = 2 V, I _C = 2 mA |
| Response Time (Fall) | t _f | - | 3 | 18 | μs | R _L = 100 Ω |
| Isolation Resistance | R _{iso} | 5 x 10 ¹⁰ | 1 x 10 ¹¹ | - | Ω | DC 500 V 40 ~ 60% R.H. |
| Floating Capacitance | C _f | - | 0.6 | 1.0 | pF | V = 0, f = 1 MHz |

* CTR = $\frac{I_C}{I_F} \times 100\%$

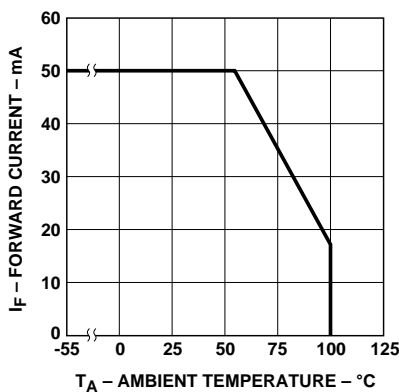


Figure 1. Forward current vs. temperature.

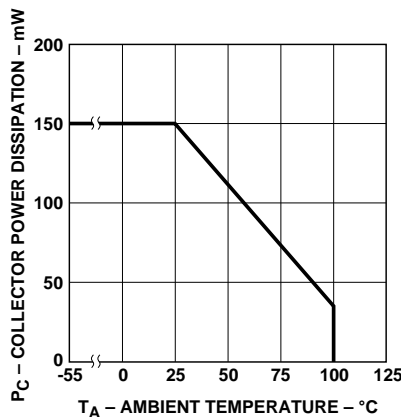


Figure 2. Collector power dissipation vs. temperature.

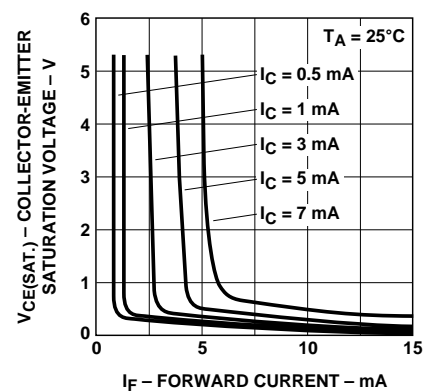


Figure 3. Collector-emitter saturation voltage vs. forward current.

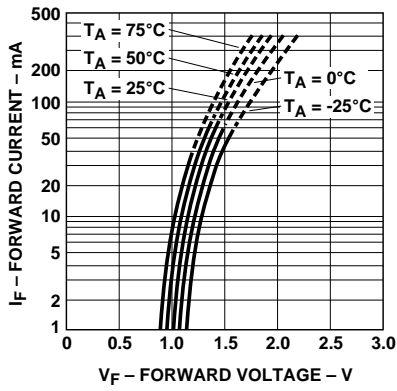


Figure 4. Forward current vs. forward voltage.

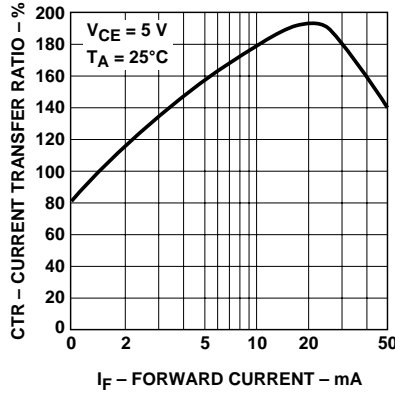


Figure 5. Current transfer ratio vs. forward current.

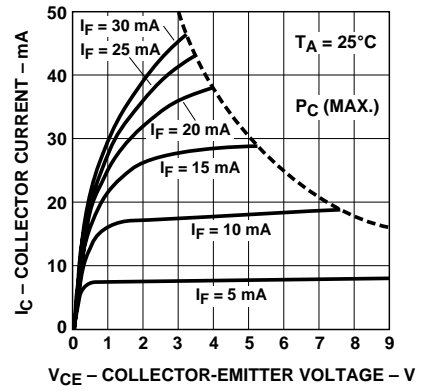


Figure 6. Collector current vs. collector-emitter voltage.

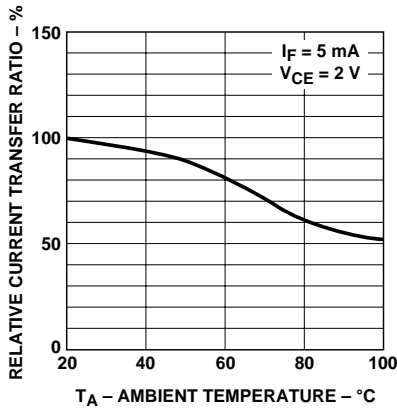


Figure 7. Relative current transfer ratio vs. temperature.

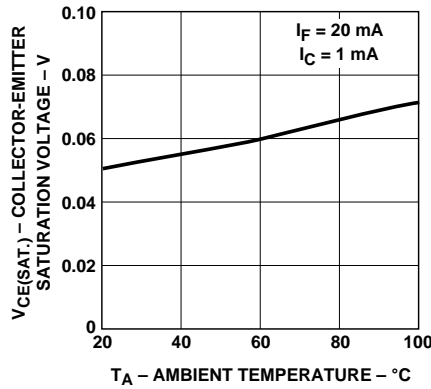


Figure 8. Collector-emitter saturation voltage vs. temperature.

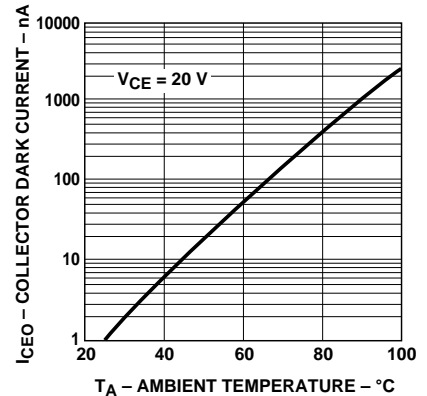


Figure 9. Collector dark current vs. temperature.

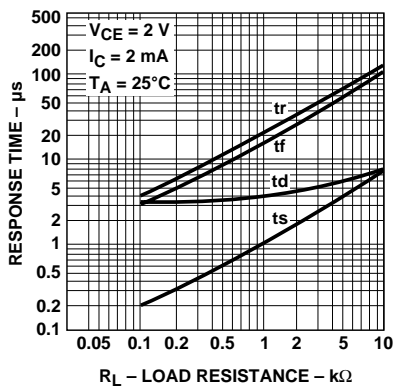


Figure 10. Response time vs. load resistance.

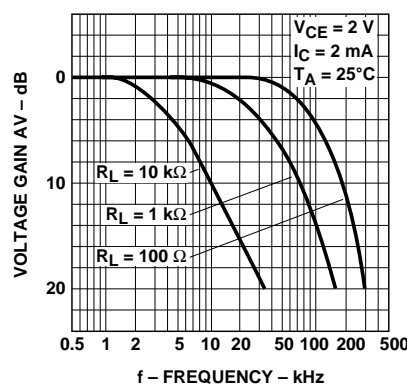
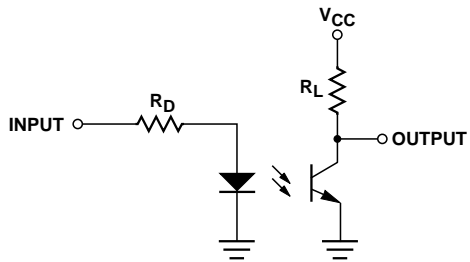
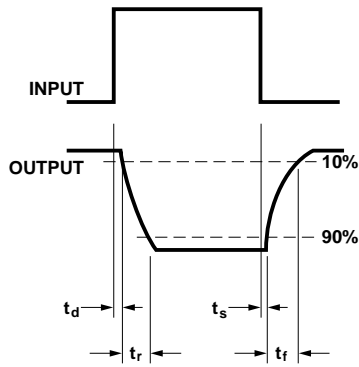
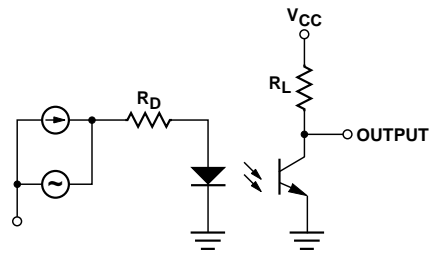


Figure 11. Frequency response.

Test Circuit for Response Time



Test Circuit for Frequency Response



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